



# PJE8407

## 20V P-Channel Enhancement Mode MOSFET

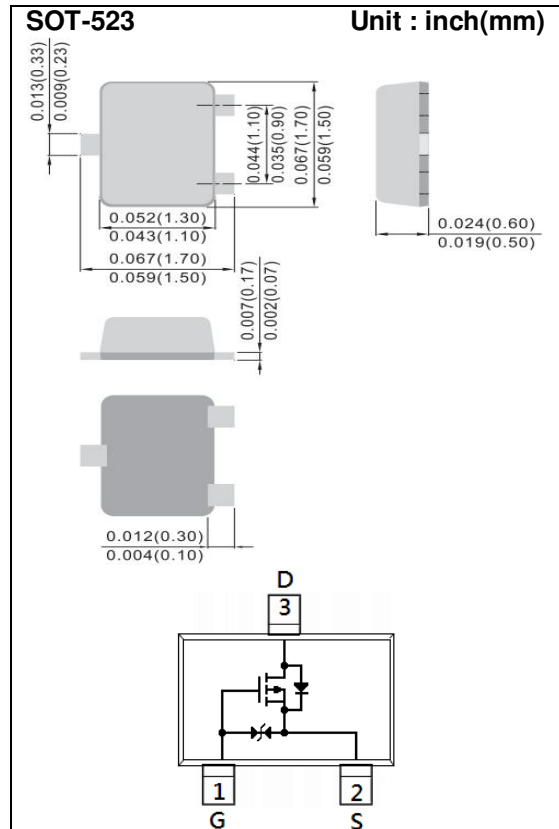
**Voltage**    **-20 V**    **Current**    **-500mA**

### Features

- Low Voltage Drive (1.2V).
- Advanced Trench Process Technology
- Specially Designed for Load switch, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case: SOT-523 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00007 ounces, 0.002 grams
- Marking: E07



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V <sub>DS</sub>	-20	V
Gate-Source Voltage	V <sub>GS</sub>	±10	V
Continuous Drain Current	I <sub>D</sub>	-500	mA
Pulsed Drain Current	I <sub>DM</sub>	-1000	mA
Power Dissipation	P <sub>D</sub>	T <sub>a</sub> =25°C	300
		Derate above 25°C	2.4
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55~150	°C
Typical Thermal resistance	R <sub>θJA</sub>	417	°C/W
- Junction to Ambient <sup>(Note 3)</sup>			



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## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.3	-0.59	-1.0	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-500mA	-	0.9	1.2	Ω
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-200mA	-	1.07	1.5	
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-100mA	-	1.25	2.2	
		V <sub>GS</sub> =-1.5V, I <sub>D</sub> =-40mA	-	1.42	3.6	
		V <sub>GS</sub> =-1.2V, I <sub>D</sub> =-10mA	-	1.7	6.0	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-16V, V <sub>GS</sub> =0V	-	-	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0V	-	±2	±10	uA
<b>Dynamic</b> (Note 5)						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =-10V, I <sub>D</sub> =-500mA, V <sub>GS</sub> =-4.5V (Note 1,2)	-	1.4	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	0.19	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	0.2	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V, f=1.0MHZ	-	38	-	pF
Output Capacitance	C <sub>oss</sub>		-	15	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	9	-	
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =-10V, I <sub>D</sub> =-500mA, V <sub>GS</sub> =-4.5V, R <sub>G</sub> =6Ω (Note 1,2)	-	7.2	-	ns
Turn-On Rise Time	t <sub>r</sub>		-	21	-	
Turn-Off Delay Time	t <sub>d(off)</sub>		-	85	-	
Turn-Off Fall Time	t <sub>f</sub>		-	116	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>	---	-	-	-500	mA
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-500mA, V <sub>GS</sub> =0V	-	-0.93	-1.3	V

**NOTES :**

1. Pulse width ≤ 300us, Duty cycle ≤ 2%
2. Essentially independent of operating temperature typical characteristics.
3. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.



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## TYPICAL CHARACTERISTIC CURVES

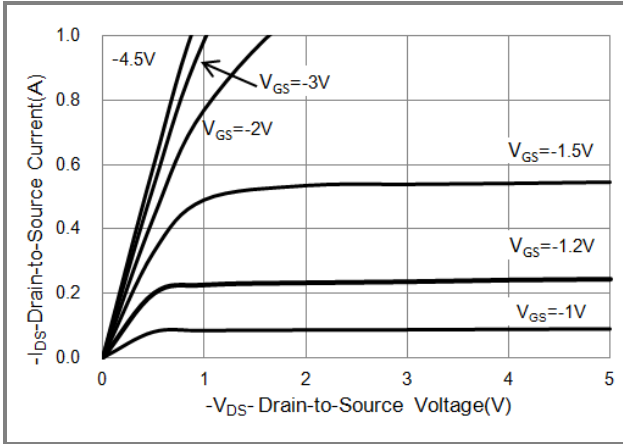


Fig.1 On-Region Characteristics

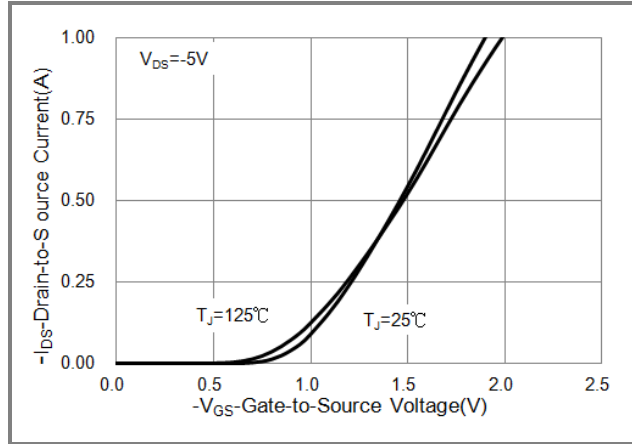


Fig.2 Transfer Characteristics

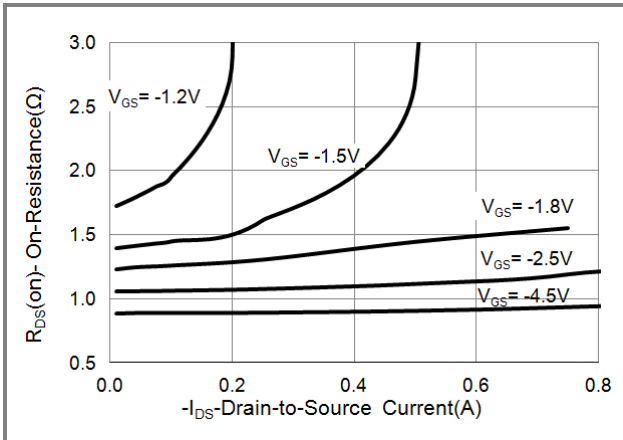


Fig.3 On-Resistance vs. Drain Current

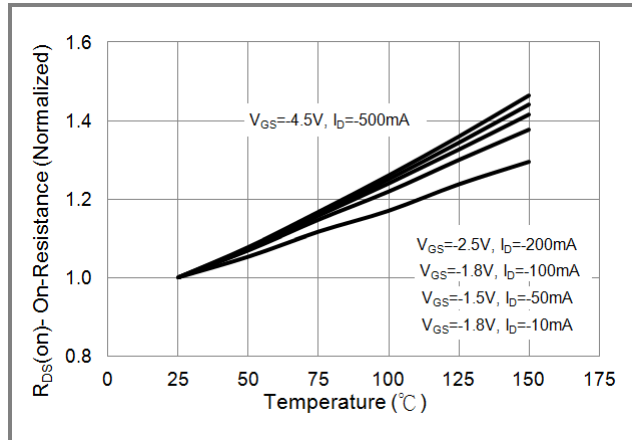


Fig.4 On-Resistance vs. Junction temperature

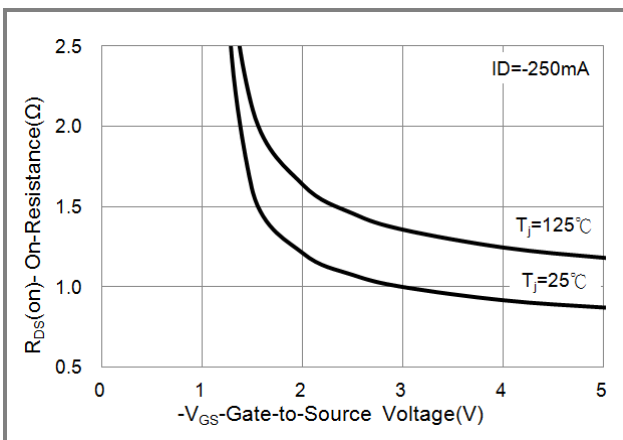


Fig.5 On-Resistance Variation with VGS.

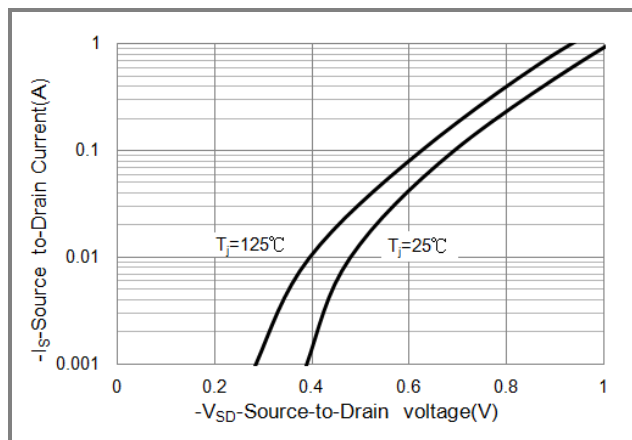


Fig.6 Body Diode Characteristics



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## TYPICAL CHARACTERISTIC CURVES

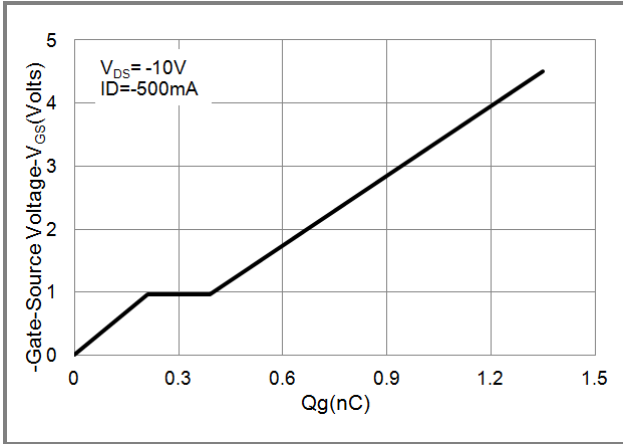


Fig.7 Gate-Charge Characteristics

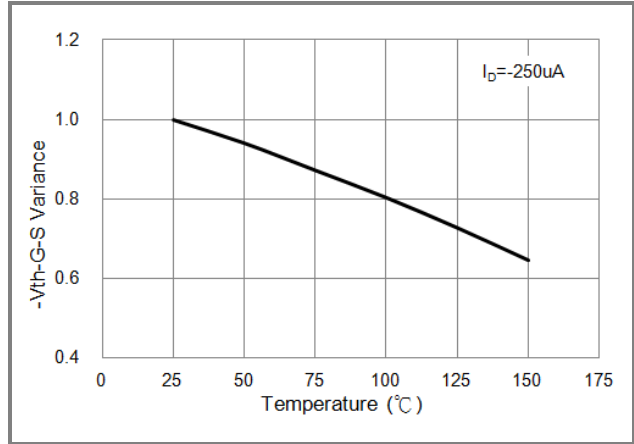


Fig.8 Threshold Voltage Variation with Temperature

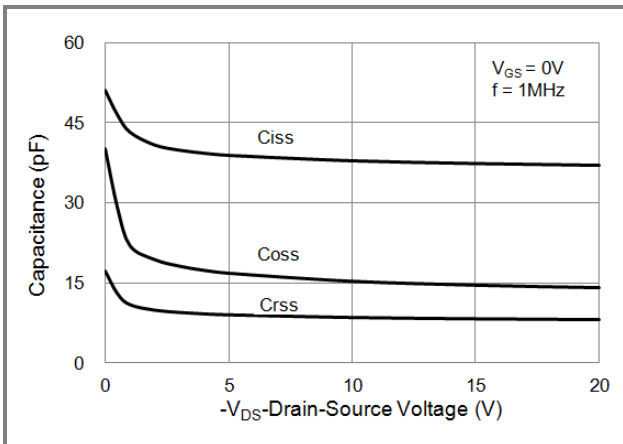


Fig.9 Capacitance vs. Drain-Source Voltage

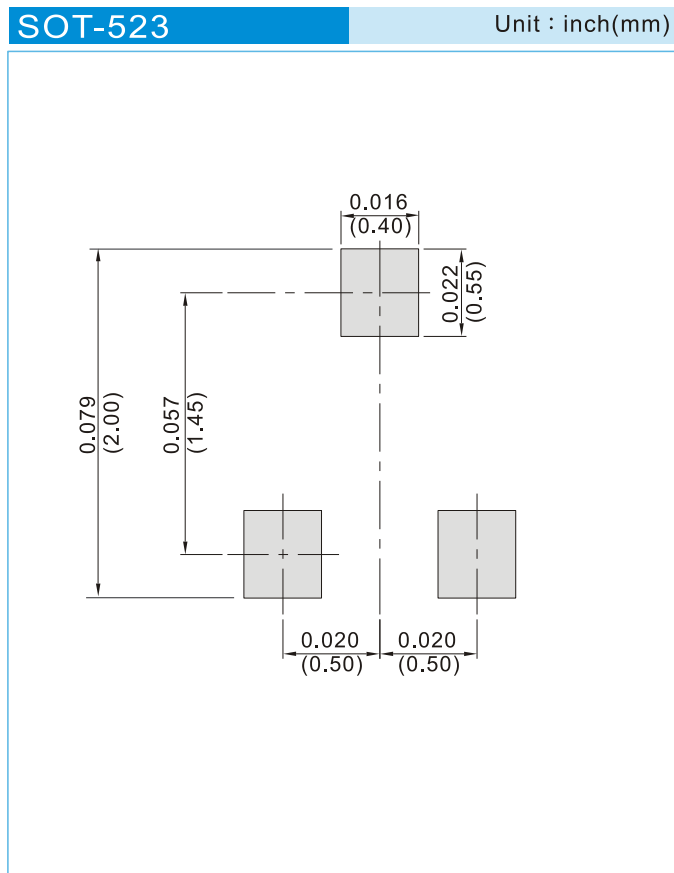


# PJE8407

## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJE8407_R1_00001	SOT-523	4K pcs / 7" reel	E07	Halogen free

## MOUNTING PAD LAYOUT





## PJE8407

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